NSN 5962-01-026-6615



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-026-6615 **Body Length:** Between 0.755 inches and 0.785 inches **Body Width:** Between 0.245 inches and 0.280 inches **Body Height:** Between 0.140 inches and 0.180 inches **Maximum Power Dissipation Rating:** 200.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable and programmable and programmed and high speed and w/open **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 16.5 volts power source **Time Rating Per Chacteristic:** 75.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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